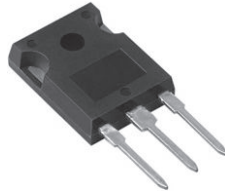
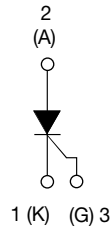




High Voltage Phase Control Thyristor, 40 A



TO-247AC



FEATURES

- Designed and qualified according to JEDEC-JESD47
- Low I_{GT} parts available
- Compliant to RoHS Directive 2002/95/EC
- 125 °C max. operating junction temperature
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)



RoHS
COMPLIANT
HALOGEN
FREE
Available

| PRODUCT SUMMARY | |
|-------------------|-------------------|
| Package | TO-247AC |
| Diode variation | Single SCR |
| $I_{T(AV)}$ | 35 A |
| V_{DRM}/V_{RRM} | 800 V, 1200 V |
| V_{TM} | 1.45 V |
| I_{GT} | 150 mA |
| T_J | - 40 °C to 125 °C |

APPLICATIONS

- Typical usage is in input rectification crowbar (soft start) and AC switch motor control, UPS, welding and battery charge

DESCRIPTION

The VS-40TPS... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

| MAJOR RATINGS AND CHARACTERISTICS | | | |
|-----------------------------------|----------------------------|-------------|------------|
| PARAMETER | TEST CONDITIONS | VALUES | UNITS |
| $I_{T(AV)}$ | Sinusoidal waveform | 35 | A |
| I_{RMS} | | 55 | |
| V_{RRM}/V_{DRM} | | 800/1200 | V |
| I_{TSM} | | 500 | A |
| V_T | 40 A, $T_J = 25\text{ °C}$ | 1.45 | V |
| dV/dt | | 1000 | V/ μ s |
| dI/dt | | 100 | A/ μ s |
| T_J | | - 40 to 125 | °C |

| VOLTAGE RATINGS | | | |
|--------------------------------|--|--|-----------------------------------|
| PART NUMBER | V_{RRM}/V_{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V | V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I_{RRM}/I_{DRM} AT 125 °C mA |
| VS-40TPS08APbF, VS-40TPS08A-M3 | 800 | 900 | 10 |
| VS-40TPS08PbF, VS-40TPS08-M3 | 1200 | 1300 | |
| VS-40TPS12APbF, VS-40TPS12A-M3 | 800 | 900 | |
| VS-40TPS12PbF, VS-40TPS12-M3 | 1200 | 1300 | |



| ABSOLUTE MAXIMUM RATINGS | | | | | |
|--|-------------------|---|---------------------------------------|--------|-------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Maximum average on-state current | $I_{T(AV)}$ | $T_C = 79\text{ }^\circ\text{C}$, 180° conduction half sine wave | | 35 | A |
| Maximum continuous RMS on-state current as AC switch | $I_{T(RMS)}$ | | | 55 | |
| Maximum peak, one-cycle non-repetitive surge current | I_{TSM} | 10 ms sine pulse, rated V_{RRM} applied | Initial $T_J = T_J$ maximum | 500 | |
| | | 10 ms sine pulse, no voltage reapplied | | 600 | |
| Maximum I^2t for fusing | I^2t | 10 ms sine pulse, rated V_{RRM} applied | | 1250 | A ² s |
| | | 10 ms sine pulse, no voltage reapplied | | 1760 | |
| Maximum $I^2\sqrt{t}$ for fusing | $I^2\sqrt{t}$ | t = 0.1 ms to 10 ms, no voltage reapplied | | 12 500 | A ² √s |
| Low level value of threshold voltage | $V_{T(TO)1}$ | $T_J = 125\text{ }^\circ\text{C}$ | | 1.02 | V |
| High level value of threshold voltage | $V_{T(TO)2}$ | | | 1.23 | |
| Low level value of on-state slope resistance | r_{t1} | | | 9.74 | mΩ |
| High level value of on-state slope resistance | r_{t2} | | | 7.50 | |
| Maximum peak on-state voltage | V_{TM} | 110 A, $T_J = 25\text{ }^\circ\text{C}$ | | 1.85 | V |
| Maximum rate of rise of turned-on current | di/dt | $T_J = 25\text{ }^\circ\text{C}$ | | 100 | A/μs |
| Maximum holding current | I_H | | | 150 | mA |
| Maximum latching current | I_L | | | 300 | |
| Maximum reverse and direct leakage current | I_{RRM}/I_{DRM} | $T_J = 25\text{ }^\circ\text{C}$ | $V_R = \text{Rated } V_{RRM}/V_{DRM}$ | 0.5 | |
| | | $T_J = 125\text{ }^\circ\text{C}$ | | 10 | |
| Maximum rate of rise of off-state voltage 40TPS08 | dV/dt | $T_J = T_J$ maximum, linear to 80 % V_{DRM} , R_g -k = Open | | 500 | V/μs |
| Maximum rate of rise of off-state voltage 40TPS12 | | | | 1000 | |

| TRIGGERING | | | | | |
|---|-------------|--|-----------------------------------|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Maximum peak gate power | P_{GM} | | | 10 | W |
| Maximum average gate power | $P_{G(AV)}$ | | | 2.5 | |
| Maximum peak gate current | I_{GM} | | | 2.5 | A |
| Maximum peak negative gate voltage | $-V_{GM}$ | | | 10 | V |
| Maximum required DC gate voltage to trigger | V_{GT} | $T_J = -40\text{ }^\circ\text{C}$ | Anode supply = 6 V resistive load | 4.0 | V |
| | | $T_J = 25\text{ }^\circ\text{C}$ | | 2.5 | |
| | | $T_J = 125\text{ }^\circ\text{C}$ | | 1.7 | |
| Maximum required DC gate current to trigger | I_{GT} | $T_J = -40\text{ }^\circ\text{C}$ | | 270 | mA |
| | | $T_J = 25\text{ }^\circ\text{C}$ | | 150 | |
| | | $T_J = 125\text{ }^\circ\text{C}$ | | 80 | |
| | | $T_J = 25\text{ }^\circ\text{C}$, for 40TPS08APbF and 40TPS12APbF | | 40 | |
| Maximum DC gate voltage not to trigger | V_{GD} | $T_J = 125\text{ }^\circ\text{C}$, $V_{DRM} = \text{Rated value}$ | | 0.25 | V |
| Maximum DC gate current not to trigger | I_{GD} | | | 6 | mA |



| THERMAL AND MECHANICAL SPECIFICATIONS | | | | |
|---|----------------|--------------------------------------|-------------|------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum junction and storage temperature range | T_J, T_{Stg} | | - 40 to 125 | °C |
| Maximum thermal resistance, junction to case | R_{thJC} | DC operation | 0.6 | °C/W |
| Maximum thermal resistance, junction to ambient | R_{thJA} | | 40 | |
| Maximum thermal resistance, case to heatsink | R_{thCS} | Mounting surface, smooth and greased | 0.2 | |
| Approximate weight | | | 6 | g |
| | | | 0.21 | oz. |
| Mounting torque | minimum | | 6 (5) | kgf · cm (lbf · in) |
| | maximum | | 12 (10) | |
| Marking device | | Case style TO-247AC | 40TPS08A | |
| | | | 40TPS12A | |
| | | | 40TPS08 | |
| | | | 40TPS12 | |

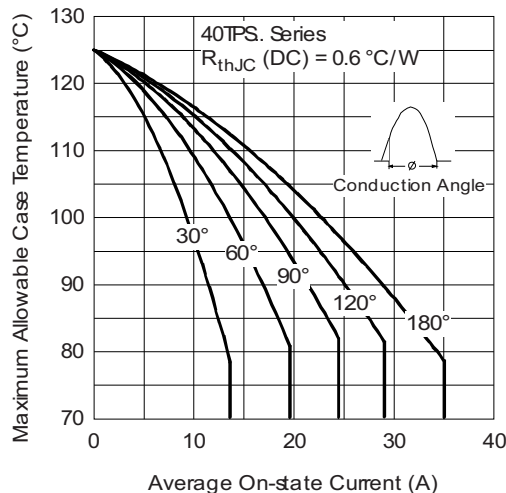


Fig. 1 - Current Rating Characteristics

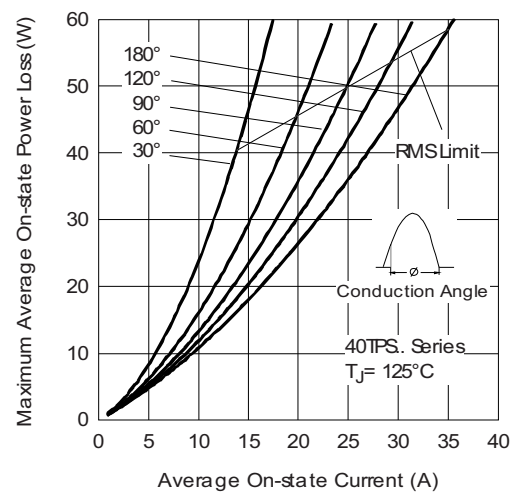


Fig. 3 - On-State Power Loss Characteristics

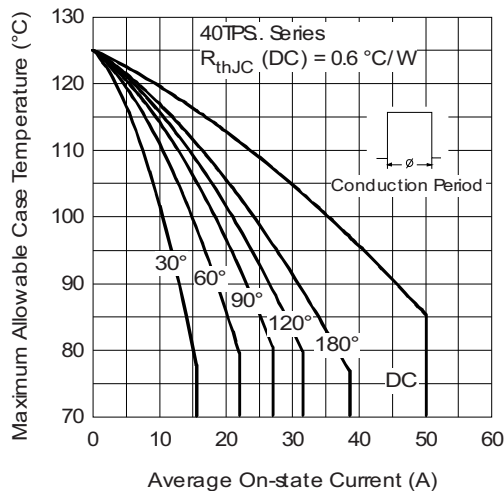


Fig. 2 - Current Rating Characteristics

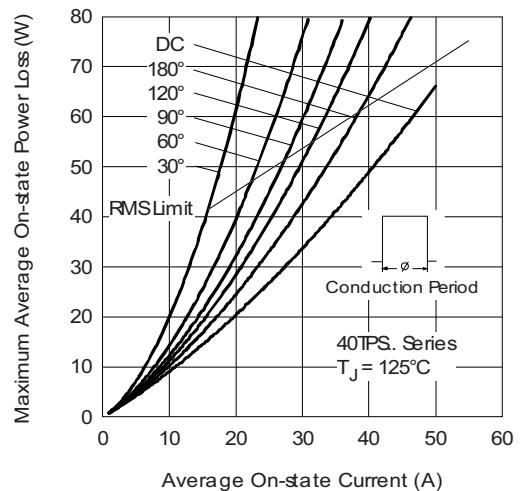


Fig. 4 - On-State Power Loss Characteristics

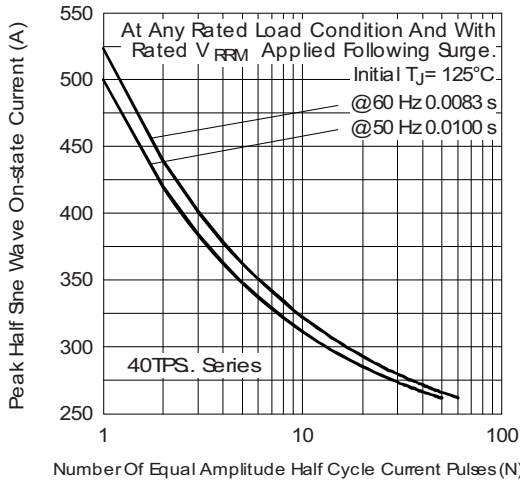


Fig. 5 - Maximum Non-Repetitive Surge Current

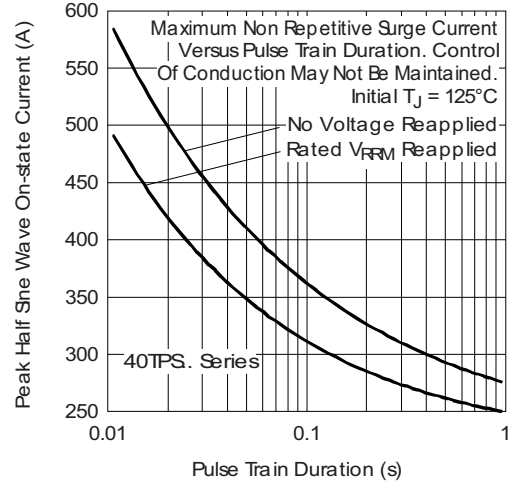


Fig. 6 - Maximum Non-Repetitive Surge Current

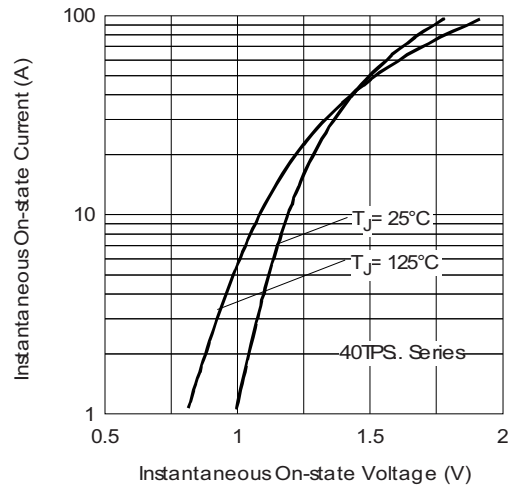


Fig. 7 - On-State Voltage Drop Characteristics

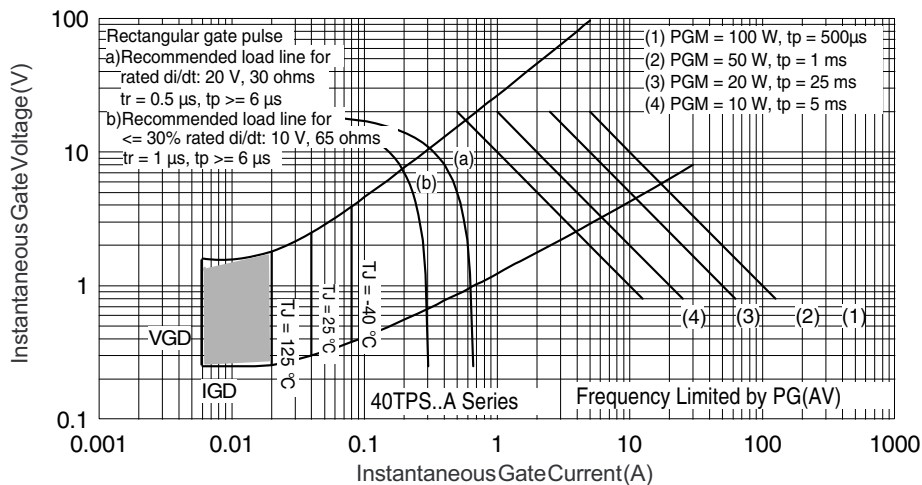


Fig. 8 - Gate Characteristics

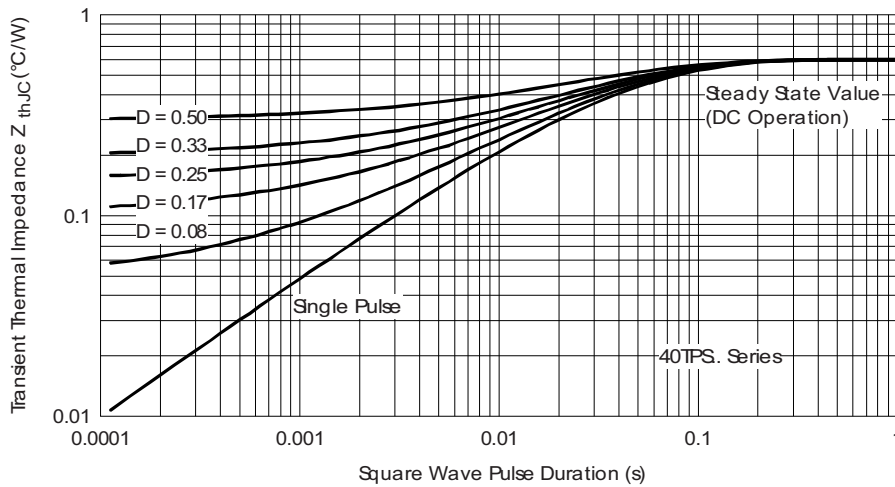


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

| | | | | | | | | |
|-------------|------------|-----------|----------|----------|----------|-----------|----------|------------|
| Device code | VS- | 40 | T | P | S | 12 | A | PbF |
| | ① | ② | ③ | ④ | ⑤ | ⑥ | ⑦ | ⑧ |

- 1** - Vishay Semiconductors product
- 2** - Current rating (40 = 40 A)
- 3** - Circuit configuration:
T = Thyristor
- 4** - Package:
P = TO-247
- 5** - Type of silicon:
S = Standard recovery rectifier
- 6** - Voltage ratings 08 = 800 V
12 = 1200 V
- 7** -
 - A = Low Igt selection 40 mA maximum
 - None = Standard Igt selection
- 8** - Environmental digit:
PbF = Lead (Pb)-free and RoHS compliant
-M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free



| ORDERING INFORMATION (Example) | | | |
|---------------------------------------|-------------------------|-------------------------------|------------------------------|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION |
| VS-40TPS08APbF | 25 | 500 | Antistatic plastic tubes |
| VS-40TPS08A-M3 | 25 | 500 | Antistatic plastic tubes |
| VS-40TPS08PbF | 25 | 500 | Antistatic plastic tubes |
| VS-40TPS08-M3 | 25 | 500 | Antistatic plastic tubes |
| VS-40TPS12APbF | 25 | 500 | Antistatic plastic tubes |
| VS-40TPS12A-M3 | 25 | 500 | Antistatic plastic tubes |
| VS-40TPS12PbF | 25 | 500 | Antistatic plastic tubes |
| VS-40TPS12-M3 | 25 | 500 | Antistatic plastic tubes |

| LINKS TO RELATED DOCUMENTS | | |
|-----------------------------------|--------------|--|
| Dimensions | | www.vishay.com/doc?95223 |
| Part marking information | TO-247AC PbF | www.vishay.com/doc?95226 |
| | TO-247AC-M3 | www.vishay.com/doc?95007 |



DIMENSIONS in millimeters and inches



| SYMBOL | MILLIMETERS | | INCHES | | NOTES | SYMBOL | MILLIMETERS | | INCHES | | NOTES |
|--------|-------------|-------|--------|-------|-------|--------|-------------|-------|-----------|-------|-------|
| | MIN. | MAX. | MIN. | MAX. | | | MIN. | MAX. | MIN. | MAX. | |
| A | 4.65 | 5.31 | 0.183 | 0.209 | | D2 | 0.51 | 1.30 | 0.020 | 0.051 | |
| A1 | 2.21 | 2.59 | 0.087 | 0.102 | | E | 15.29 | 15.87 | 0.602 | 0.625 | 3 |
| A2 | 1.50 | 2.49 | 0.059 | 0.098 | | E1 | 13.72 | - | 0.540 | - | |
| b | 0.99 | 1.40 | 0.039 | 0.055 | | e | 5.46 BSC | | 0.215 BSC | | |
| b1 | 0.99 | 1.35 | 0.039 | 0.053 | | FK | 2.54 | | 0.010 | | |
| b2 | 1.65 | 2.39 | 0.065 | 0.094 | | L | 14.20 | 16.10 | 0.559 | 0.634 | |
| b3 | 1.65 | 2.37 | 0.065 | 0.094 | | L1 | 3.71 | 4.29 | 0.146 | 0.169 | |
| b4 | 2.59 | 3.43 | 0.102 | 0.135 | | N | 7.62 BSC | | 0.3 | | |
| b5 | 2.59 | 3.38 | 0.102 | 0.133 | | ΦP | 3.56 | 3.66 | 0.14 | 0.144 | |
| c | 0.38 | 0.86 | 0.015 | 0.034 | | ΦP1 | - | 6.98 | - | 0.275 | |
| c1 | 0.38 | 0.76 | 0.015 | 0.030 | | Q | 5.31 | 5.69 | 0.209 | 0.224 | |
| D | 19.71 | 20.70 | 0.776 | 0.815 | 3 | R | 4.52 | 5.49 | 1.78 | 0.216 | |
| D1 | 13.08 | - | 0.515 | - | 4 | S | 5.51 BSC | | 0.217 BSC | | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c



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